Q. No.	Expected Answer / Value Points	Marks	Total Marks
			Marks
Set1 Q1	It is defined as the opposition to the flow of current in ac circuits offered by a		
Set2 Q5 Set3 O4	capacitor.		
5013 Q I	<u>Alternatively:</u>		
	$v - \frac{1}{2}$	1/2	
	$\Lambda_c - \omega c$		
	S.I Unit : ohm	1/2	1
Set1 Q2	Zero	1	1
Set2 Q1			
Set3 Q5			
Set1 Q3	Converging (Convex Lens), (Also accept if a student writes it as a diverging	1	1
Set2 Q2	Lens or Concave lens (Since hindi translation does not match with English		
Set3 Q1	version)		
Set1 Q4	Side bands are produced due to the superposition of carrier waves of		
Set2 Q3	frequency ω_c over modulating / audio signal of frequency ω_m .	1	
Set3 Q2			
	<u>Alternatively:</u>		
	(Credit may be given if a student mentions the side bands as $\omega_c \pm \omega_m$)		1
Set1 Q5	DE : Negative resistance region	1⁄2	
Set2 Q4	AB : Where Ohm's law is obeyed.(Also accept BC)	1/2	1
5013 Q3			
Set1 Q6	Determination of ratio (i) accelerating potential 1		
Set2 Q10 Set3 Q9	(ii) speed 1		
	h h ²		
	(i) $\lambda = \frac{n}{\sqrt{2mqV}} \implies V = \frac{n}{2mq\lambda^2}$	1/2	
	$m_{lpha}=4m_p$, $q_{lpha}=2q_p$		
	$= > \frac{V_p}{V_\alpha} = \frac{m_\alpha \ q_\alpha}{m_p q_p}$		
	$=\frac{4m_p \times 2q_p}{m_p q_p}$		
	···*p~*p		
	= 8:1	1/2	

MARKING SCHEME

	(ii) $\lambda = \frac{h}{mv} \implies v = \frac{h}{m\lambda}$		1⁄2	
	$=> \qquad \frac{V_p}{V_\alpha} = \frac{m_\alpha}{m_p} = 4$		1/2	2
Set1 Q7 Set2 Q6 Set3 O10	Showing that the radius of orbit varies as	n ² 2		
	$\frac{mv^2}{r} = \frac{1}{4\pi \in_0} \frac{e^2}{r^2}$		1⁄2	
	Or $mv^2r = \frac{1}{4\pi\epsilon_0} e^2$ ((i)		
	$mvr = \frac{nh}{2\pi}$		1⁄2	
	$m^2 v^2 r^2 = \frac{n^2 h^2}{4\pi^2}$ (ii)	1/	
	Divide (ii) by (i)		1/2	
	$\mathrm{mr} = \frac{n^2 h^2}{4\pi^2} \times \frac{4\pi \epsilon_0}{e^2}$			
	$\therefore r = \frac{n^2 h^2}{4\pi^2 m e^2} \cdot 4\pi \in_0$		1/2	
	$\therefore r \propto n^2$ (Give full credit to any other correct alternative)	ative method)		2
Set1 Q8 Set2 Q7 Set3 O6	Distinction between intrinsic & extrinsic s	semiconductor 2		
	Intrinsic Semiconductor	Extrinsic Semiconductor		
			1	
	(1) Without any impurity (atoms.	pentavalent impurity atoms.	1	
	(ii) $n_e = n_h$ (iii)	ii) $n_e \neq n_h$	1	
	(Any other correct distinguishing features.))		
Set1 O9				2
Set2 Q8 Set3 Q7	Derivation of the required condition	2		

Page 2 of 23

$\frac{1}{f} = \frac{1}{v} + \frac{1}{u}$	1/2	
For concave mirror $f < 0$ and $u < 0$ As object lies between f and $2f$ (i) At $u = -f$		
$\frac{1}{v} = -\frac{1}{f} + \frac{1}{f}$		
$=> v = \infty$ At $u = -2f$ $=> \frac{1}{v} = -\frac{1}{f} + \frac{1}{2f} = -\frac{1}{2f}$	1/2	
=> v = -2 f	1⁄2	
=> Hence, image distance $v \ge -2 f$	1⁄2	2
Since v is negative therefore the image is real.		2
Alternative Method	1⁄2	
$\frac{1}{f} = \frac{1}{v} + \frac{1}{u}$ For Concave mirror f < 0, u < 0	1/2	
$\because 2f < u < f$		
$\Rightarrow \frac{1}{2f} > \frac{1}{u} > \frac{1}{f}$		
$\frac{1}{2f} - \frac{1}{f} > \frac{1}{u} - \frac{1}{f} > \frac{1}{f} - \frac{1}{f}$		
$\Rightarrow -\frac{1}{2f} - \frac{1}{v} > 0 \qquad \qquad \because \frac{1}{u} - \frac{1}{f} = \frac{1}{-v}$		
$\Rightarrow \frac{1}{2f} < \frac{1}{\nu} < 0$	1/2	
$\Rightarrow v < 0$ \therefore image is real	1/2	
Also $v > 2f$ image is formed beyond $2f$. (Any alternative correct method should be given full credit.)	, 2	2



	For loop CBDC		
	$-I_2R_4 + 0 + I_1R_3 = 0$ (ii)		
	=> from equation (i)		
	$\frac{I_1}{I_1} = \frac{R_1}{I_1}$		
	$I_2 R_2$		
	From equation (1) $L = R$.		
	$\frac{T_1}{I} = \frac{\pi 4}{D}$	1/2	
	$I_2 K_3$		
	$R_1 \qquad R_4$		
	$\therefore \frac{1}{R_2} = \frac{1}{R_3}$	1⁄2	2
Set1 Q11			
Set2 Q19	Name of the parts of e.m. spectrum for a,b,c $\frac{1}{2} + \frac{1}{2} + \frac{1}{2}$		
Set3 Q10	Production		
	(a) Microwaye	1/2	
	Production · Klystron/magnetron/Gunn diode (any one)	1/2	
	Troduction - Thysiton, magnetion, Cann aloue (any one)	, 2	
	(b) Infrared Radiation	1/2	
	Production : Hot bodies / vibrations of atoms and molecules (any one)	1/2	
		1/	
	(C) X-Kays Production : Rombarding high energy electrons on metal target/ y ray	¹ /2 1/2	3
	tube/inner shell electrons(any one)	72	5
	tuoo, miler shen erectrons(any one).		
Set1 Q12			
Set2 Q20	(i) Calculation of angular magnification $1\frac{1}{2}$		
Sets Q17	(ii) Calculation of image of diameter of Moon $1\frac{1}{2}$		
	Angular Magnification		
	f _o	1	
	$m = \frac{f_{c}}{f_{c}}$		
)e		
	$=\frac{15}{10^{-2}}=1500$	1/2	
	10 -2		

	$h_{o} \propto f_{0} \rightarrow f_{0}$ $u_{0} \qquad h_{i}$	1⁄2 1⁄2	
	Angular size of the moon $=\left(\frac{3.48 \times 10^6}{3.8 \times 10^8}\right) = \frac{3.48}{3.8} \times 10^{-2}$ radian \therefore Angular size of the image $=\left(\frac{3.48}{3.8} \times 10^{-2} \times 1500\right) =$ radian	1⁄2	3
	Diameter of the image $=\frac{3.48}{3.8} \times 15 \times focal \ length \ of \ eye \ piece$ $=\frac{3.48}{3.8} \times 15 \times 1cm$ =13.7 cm (Also accept alternative correct method.)		
Set1 Q13 Set2 Q21 Set3 Q18	(i)Einstein's Photoelectric equation $\frac{1}{2}$ (ii)Important features $\frac{1}{2} + \frac{1}{2}$ (iii)Derivation of expressions for λ_0 and work function $\frac{1}{2}$		
	$hv = \varphi_{o+} k_{max}$ or $hv = hv_0 + \frac{1}{2}mv_{max}^2$	1⁄2	
	 Important features (i) k_{max} depends linearly on frequency v. (ii) Existence of threshold frequency for the metal surface. (Any other two correct features.) 	1/2 1/2	
	$h\nu = \varphi_{o+} k_{max}$ $\frac{hc}{\lambda_1} = \frac{hc}{\lambda_0^+} k_{max} (i)$		
	$\frac{hc}{\lambda_2} = \frac{hc}{\lambda_0^+} 2k_{max} (ii)$ From (i) and (ii)	1⁄2	
	$\frac{2hc}{\lambda_1} - \frac{hc}{\lambda_2} = \frac{hc}{\lambda_0}$		

$$\frac{1}{\lambda_{0}} = \left(\frac{2}{\lambda_{1}} - \frac{1}{\lambda_{2}}\right)$$

$$\lambda_{0} = \frac{\lambda_{1}\lambda_{2}}{2\lambda_{2} - \lambda_{1}}$$
Work function $\varphi_{0} = \frac{hc}{\lambda_{0}} = \frac{hc(2\lambda_{2} - \lambda_{1})}{\lambda_{1}\lambda_{2}}$

$$3$$
Work function $\varphi_{0} = \frac{hc}{\lambda_{0}} = \frac{hc(2\lambda_{2} - \lambda_{1})}{\lambda_{1}\lambda_{2}}$

$$3$$
Set 014
(i) Drawing of trajectory
(ii) Explanation of information on the size of nucleus
(iii) Proving that nuclear density is independent of A 1 1/2)
$$\frac{1}{\lambda_{0}} = \frac{1}{\lambda_{0}} + \frac{1}{\lambda_{0}} +$$

	OR		
	Distinction between nuclear fission and nuclear fusion $\frac{1}{2} + \frac{1}{2}$ Showing release of energy in both processes $\frac{1}{2}$ Calculation of release of energy1 $\frac{1}{2}$		
	The breaking of heavy nucleus into smaller fragments is called nuclear fission; the joining of lighter nuclei to form a heavy nucleus is called nuclear fusion.	1/2 + 1/2	
	Binding energy per nucleon, of the daughter nuclei, in both processes, is more than that of the parent nuclei. The difference in binding energy is released in the form of energy. In both processes some mass gets converted into energy.	1/2	
	<u>Alternativey:</u> In both processes, some mass gets converted into energy.		
	Energy Released		
	Q = $[m(_1^2H) + m(_1^3H) - m(_2^4He) - m(n)] \ge 931.5 \text{ MeV}$	1⁄2	
	= [2.014102 + 3.016049 - 4.002603 - 1.008665] x 931.5 MeV	1/2	
	= 0.018883 x 931.5 MeV		
	= 17.59 MeV	1/2	3
Set1 Q15 Set2 Q11 Set3 Q20	Drawing Block diagram of detector1Showing detection of Message signal from Input AM Wave2		
	$\xrightarrow{\text{AM Wave}} \xrightarrow{\text{RECTIFIER}} \xrightarrow{\text{ENVELOPE}} \xrightarrow{m(t)} \xrightarrow{m(t)} \xrightarrow{\text{OUTPUT}} \xrightarrow{(a)} \xrightarrow{(b)} \xrightarrow{(c)} ($	1	
	time time time	1+1	
	AM input wave Rectified wave Output (without RF component)	1	
	[Note: Award these 3 marks irrespective of the way the student attempts the question.]		3
Set1 Q16 Set2 Q12	Drawing of Plots of Part (i) & (ii) $\frac{1}{2} + \frac{1}{2}$		
Set3 Q21	Finding the values of emf and internal resistance $1+1$		



Page 9 of 23

Energy stored in a capacitor		
$E = \frac{1}{2}CV^2$	1⁄2	
In series combination		
$0.045 = \frac{1}{2} \frac{c_1 c_2}{c_1 + c_2} (100)^2$		
$ = \frac{c_1 c_2}{c_1 + c_2} = 0.09 \text{ x } 10^{-4} \qquad \dots \dots (i) $	1⁄2	
In Parallel combination		
$0.25 = \frac{1}{2}(C_1 + C_2) (100)^2$		
$^{=>}C_1 + C_2 = 0.5 \text{ x } 10^{-4} \qquad \dots \dots (ii)$	1⁄2	
On simplifying (i) & (ii)		
$C_1 C_2 = 0.045 \text{ x } 10^{-8}$		
$(C_1 - C_2)^2 = (C_1 + C_2)^2 - 4C_1C_2$		
$= (0.5 \times 10^{-4})^2 - 4 \times 0.045 \times 10^{-8}$		
$= 0.25 \text{ x } 10^{-8} - 0.180 \text{ x } 10^{-8}$		
$(C_1 - C_2)^2 = 0.07 \times 10^{-8}$		
$(C_1 - C_2) = 2.6 \times 10^{-5} = 0.26 \times 10^{-4} \dots$ (iii)		
From (ii) and (iii) we have	1/2	
$=> C_1 = 0.38 \text{ x } 10^{-4} \text{ F } \& C_2 = 0.12 \text{ x } 10^{-4} \text{ F}$	/ _	
Charges on capacitor C_1 and C_2 in Parallel combination		
$Q_1 = C_1 V = (0.38 \text{ x } 10^{-4} \text{ x } 100) = 0.38 \text{ x } 10^{-2} \text{ C}$	1⁄2	
$Q_2 = C_2 V = (0.12 \text{ x } 10^{-4} \text{ x } 100) = 0.12 \text{ x } 10^{-2} \text{ C}$ [Note: If the student writes the relations/ equations $E = \frac{1}{2} CV^2$	1/2	

Page 10 of 23

	And $0.04F = \frac{1}{C_1 C_2} (100)^2$		
	And $0.045 = \frac{1}{2} \left(\frac{1}{C_1 + C_2} \right) (100)$		
	$0.25 = \frac{1}{2}(C_1 + C_2)(100)^2$		
	But is unable to calculate C_1 and C_2 , award him/her full 2 marks.		
	Also if the student just writes		
	$Q_1 = C_1 V = C_1(100)$ and $Q_2 = C_2 V = C_2(100)$		3
	Award him/her one mark for this part of the question.]		
Set1 Q18	Working Principle 1 Finding the required registeries 1		
Set2 Q14	Finding the resistance G of the Galvanometer 1		
Set3 Q11			
	Working Principle: A current carrying coil experiences a torque when placed in a magnetic field which tends to rotate the coil and produces an angular		
	deflection.	1	
	$V = I\left(G + R_1\right)$		
	$\frac{V}{2} = I \left(G + R_2 \right)$	1/2	
	$\implies 2 = \frac{G + R_1}{G + R_2}$		
	$=>G=R_1-2R_2$	1⁄2	
	Let R_3 be the resistance required for conversion into voltmeter of range 2V $\therefore 2V = I_g (G + R_3)$		
	Also $V = I_g (G + R_1)$	1/2	
	$\therefore 2 = \frac{1}{G + R_1}$	/2	
0.1.010	$\therefore R_3 = G + 2R_1 = R_1 - 2R_2 + 2R_1 = 3R_1 - 2R_2$	1⁄2	3
Set1 Q19 Set2 Q15	Eabrication of photodiode $\frac{1}{2}$		
Set3 Q12	Working with suitable diagram $1\frac{1}{2}$		
	Reason 1		
	It is fabricated with a transparent window to allow light to fall on diode.	1/2	
	When the photodiode is illuminated with photons of energy $(h\nu > E_{\sigma})$ greater		
	than the energy gap of the semiconductor, electron – holes pairs are generated. These gets separated due to the Junction electric field (before they recombine) which produces an emf.	1	



Page 12 of 23

17/03/15 4:30 p.m.

	The value of input resistance is determined from the slope of L verses $V_{}$		
	plot at constant V_{CE} .		
	The value of current amplification factor is obtained from the slope of collector Ic verses V_{CE} plot using different values of I_B .	1⁄2	
	(If a student uses typical charateristics to determine these values, full credit of one mark should be given)		3
Set1 Q21			
Set2 Q17 Set3 Q14	Finding the spacing between two slits1Effect on wavelength and frequency of reflected and refracted light 2		
	(a) Angular width of fringes $\theta = \lambda/d$, where d = separation between two slits	1⁄2	
	Here $\theta = 0.1^\circ = 0.1 \text{ x} \frac{\pi}{180}$ radian		
	$\therefore d = \frac{600 \times 10^{-9} \times 180}{0.1 \times \pi} m$ = 3.43 x 10 ⁻⁴ m = 0.34m	1/2	
	(b)		
	(U) For Pofloctod light:		
	<u>For Kenetieu light.</u> Wavelength remains same	1⁄2	
	Frequency remains some	1⁄2	
	For Defracted light:		
	<u>For Kerracted light.</u> Wavelength decreases	1⁄2	
	Frequency remains some	1/2	3
	Frequency remains same		
Set1 Q22			
Set2 Q18	Change in the Brightness of the bulb in cases (1), (11) & (11) $\frac{1}{2} + \frac{1}{2} + \frac{1}{2}$		
Sets Q15	Justification $\frac{1}{\sqrt{2} + \frac{1}{\sqrt{2}} + \frac{1}{\sqrt{2}}}{\sqrt{2} + \frac{1}{\sqrt{2}} + \frac{1}{\sqrt{2}}}$		
	(i) Increases	1/	
	$X_L = \omega L$	¹ /2	
	As number of turns decreases, L decreases, nence current through	¹ /2	
	(ii) Depresses	72	
	(II) Decreases	1/2	
	current through the hulb decreases / Voltage across hulb decreases	$\frac{1}{2}$	
	(iii) Increases	/2	
	Under this condition $(X_c = X_t)$ the current through the hulb will	1/2	3
	become maximum / increase.	, -	
Set1 Q23			
Set2 Q23	(i) Name of device and Principle of working $\frac{1}{2} + 1$		
Set3 Q23	(11) Possibility and explanation $\frac{1}{2}$		
	(111) Values displayed by students and teachers 1+1		

	(i) Transformer Working Principle: Mutual induction	1⁄2	
	Whenever an alternative voltage is applied in the primary windings, an emf is induced in the secondary windings.	1	
	(ii) No, There is no induced emf for a dc voltage in the primary	1⁄2	
	 (iii) Inquisitive nature/ Scientific temperament (any one) Conceren for students / Helpfulness / Professional honesty(any one) (Any other relevant values) 	1 1	4
Set1 Q24 Set2 Q26 Set3 Q25	 (a) Statement of Ampere's circuital law 1 Expression for the magnetic field 1 1¹/₂ (b) Depiction of magnetic field lines and specifying polarity 1¹/₂ + 1¹/₂ Showing the solenoid as bar magnet 1 1¹/₂ 		
	(a) Line integral of magnetic field over a closed loop is equal to the μ_0 times the total current passing through the surface enlosed by the loop. Alternatively $\oint \vec{B} \cdot \vec{dl} = \mu_0 I$	1	
	ј 21.00 рој 1 в		
		1/2	
	(b)		
	Let the current flowing through each turn of the toroid be <i>I</i> . The total number of turns equals $n.(2\pi r)$ where <i>n</i> is the number of turns per unit length. Applying Ampere's circuital law, for the Amperian loop, for interior points.		
Page	14 of 23 Final Draft 17/0	3/15 4:30	p.m.

	$\oint \vec{B}. \vec{dl} = \mu_0(n2\pi rI)$		
	$\oint Bdlcos0 = \mu_0 n 2\pi r I$	1/2	
	$=>B \ge 2\pi r = \mu_0 n \ 2\pi r I$		
	$B = \mu_0 n I$	1⁄2	
	(b)		
		1/2 + 1/2	
	The solenoid contains N loops, each carrying a current I. Therefore, each loop acts as a magnetic dipole. The magnetic moment for a current I, flowing in loop of area (vector) \mathbf{A} is given by $\mathbf{m} = \mathbf{I}\mathbf{A}$	1/2 1/2	
	The magnetic moments of all loops are aligned along the same direction. Hence, net magnetic moment equals N1A.	1⁄2	5
	OR		
	 (a) Definition of mutual inductance and S.I. unit (b) Derivation of expression for the mutual inductance of two long coaxial solenoids (c) Finding out the expression for the induced emf 		
	(a) $\phi = MI$ Mutual inductance of two coils is equal to the magnetic flux linked with one coil when a unit current is passed in the other coil.	1	
	Alternatively,		
	$e = -M \frac{dI}{dt}$		
	Mutual inductance is equal to the induced emf set up in one coil when the rate of change of current flowing through the other coil is unity.		
	SI unit : henry / (Weber ampere ⁻¹) / (volt second ampere ⁻¹)		
Page	15 of 23 Final Draft 17/	03/15 4:30) p.m.



$$\begin{array}{c|c} \vdots \frac{d\Phi_{3}}{dt} = M\frac{dt_{2}}{dt} \\ \Rightarrow e = -M\frac{dt_{2}}{dt} \\ \Rightarrow e = -M\frac{dt_{2}}{dt} \\ \end{array}$$

Page 17 of 23

Final Draft

17/03/15 4:30 p.m.



Page 18 of 23







Page 21 of 23

17/03/15 4:30 p.m.



	$P = X_e E$	1/2	
	B (i) Net Force on the charge $\frac{Q}{2}$, placed at the centre of the shell, Is zero.	1/2	
	Force on charge '2Q' kept at point A		
	$F = E \times 2Q = \frac{1\left(\frac{3Q}{2}\right)2Q}{4\pi\varepsilon_0 r^2} = \frac{(K)3Q^2}{r^2}$	1/2	
	Electric flux through the shell		
	$\phi = \frac{Q}{2\varepsilon_0}$	1	5
			1